



Attorney Docket SEL 192

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of Yamazaki et al.)
Serial No.: 09/610,217)
Filed: July 5, 2000)
For: Semiconductor Device And)
Fabrication Method Thereof)
Art Unit: 2812)
Examiner: R. Booth)

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Shannon Wallace

Name of applicant, assignee, or Registered Rep.

Shannon Wallace 7/2/03

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Date

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Commissioner for Patents
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Alexandria, VA 22313-1450

July 2, 2003

AMENDMENT B (AFTER FINAL)

Sir:

In response to the Final Rejection of March 6, 2003, a one month extension of time being separately submitted, please enter the following amendment in the above-identified application.

IN THE CLAIMS:

Please amend the claims as follows:

29 (Twice Amended). A method of fabricating a semiconductor device comprising:
forming a first semiconductor island and a second semiconductor island and a third semiconductor island over a substrate;
forming a first low concentration n-type impurity region and a second low concentration n-type impurity region and a third low concentration n-type impurity region respectively in said first semiconductor island and said second semiconductor island and said third semiconductor island by

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